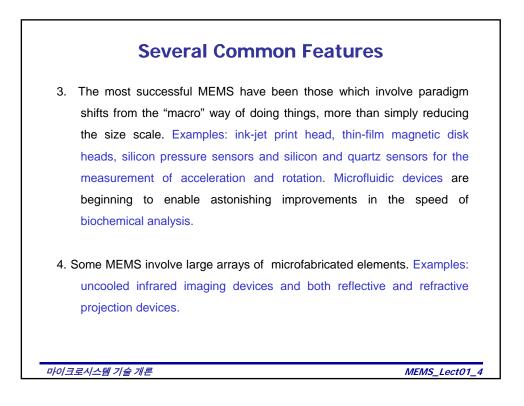
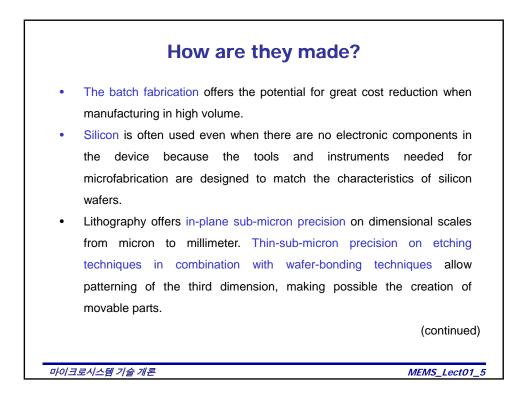
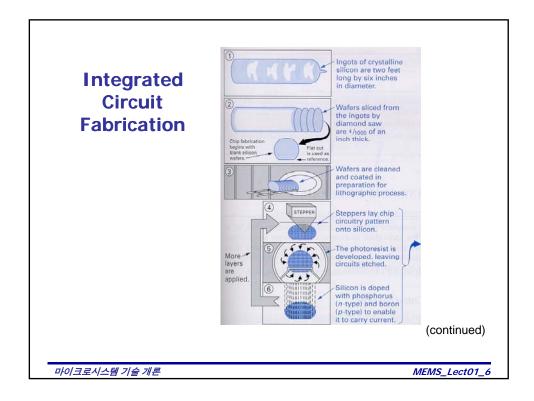
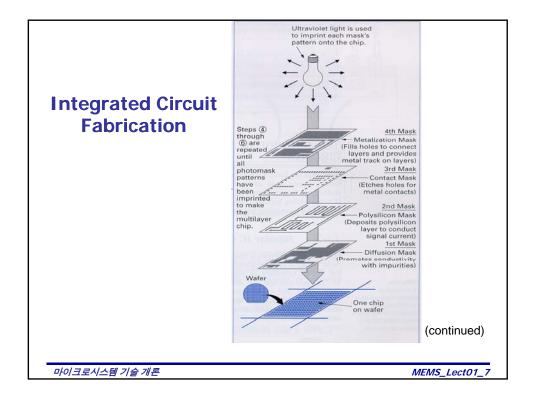


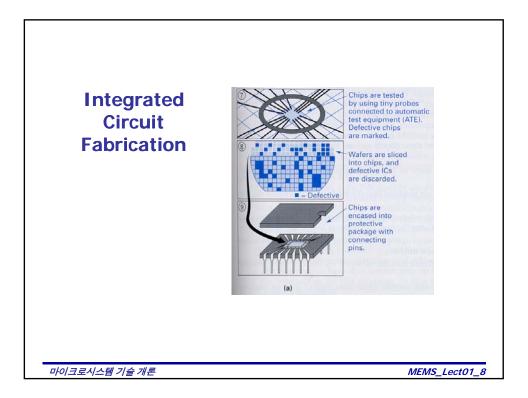
Several Common Features	5
<ol> <li>MEMS involve both electronic and non-electronic element functions that can include signal acquisition, signal actuation, display, and control. They can also serve performing chemical and biochemical reactions and a</li> </ol>	gnal processing, e as vehicles for
2. MEMS are "systems", which means that important sys as packaging, system partitioning into components, ca to-noise ratio, stability, and reliability must be confronte	alibration, signal- ed.
마이크로시스템 기술 개론	(continued)

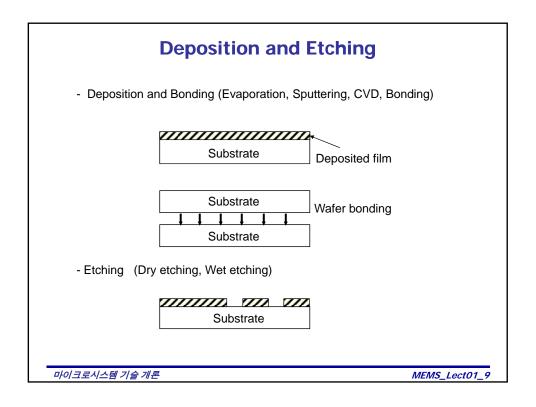


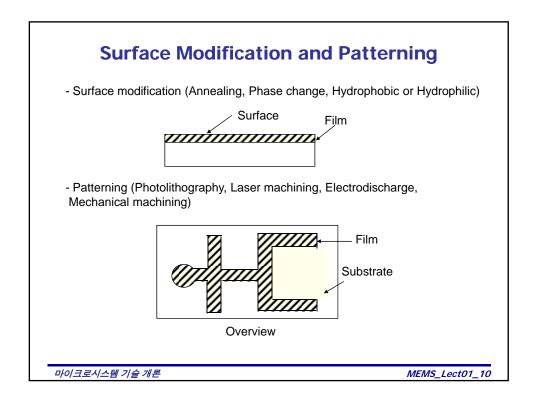


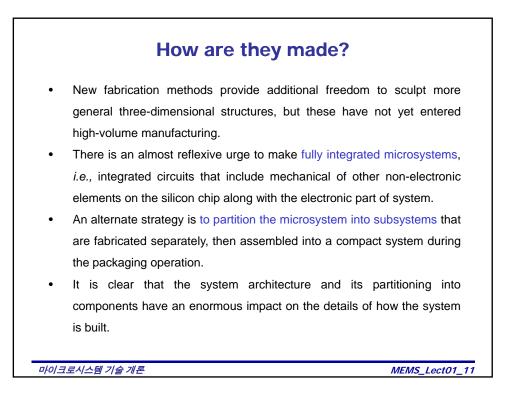


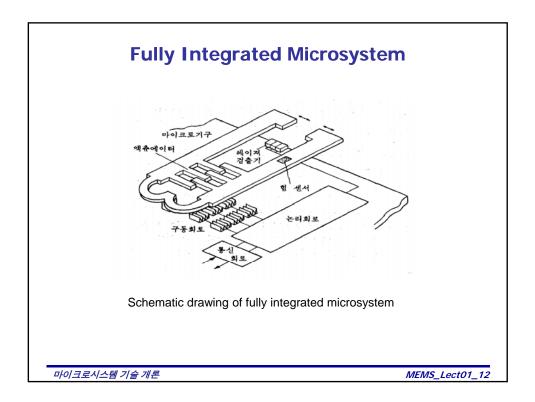


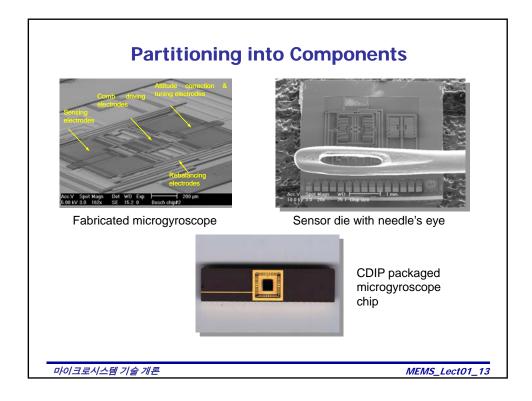


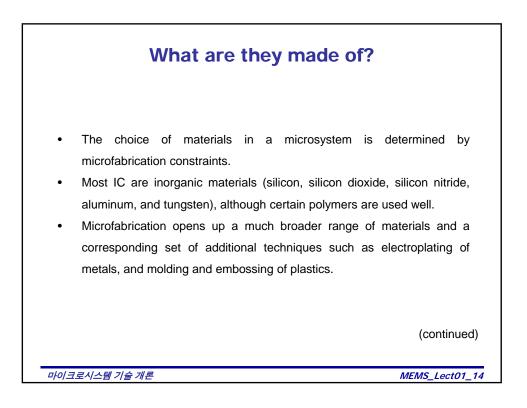












명칭	용 도	제작방법	특 징
실리콘	구조재	반도체소자 제조공정	논리회로와 집적화 가능
다결정실리콘	구조재	반도체소자 제조공정	고농도 B 첨가 실리콘 막 사 이
실리콘질화막	윤활막	반도체소자 제조공정	절연재
실리콘산화막	희생층	반도체소자 제조공정	실리콘 질화막 사이
PSG (Phospho Silicate Glass)	희생층	반도체소자 제조공정	다결정 실리콘 막 사이, 실리콘 질화막과 실리콘 기 판 사이
텅스텐	구조재	반도체소자 제조공정	HF에 녹지않고 연성이 있음
몰리브덴	구조재	반도체소자 제조공정	연성이 있음
Silicate Glass) 텅스텐	구조재	반도체소자 제조공정	판 사이 HF에 녹지않고 연성이 있음

명 칭	용 도	제작 방법	특 징
Ni, Cu, Au	구조재	전해도금,LIGA	전해도금
NiFe	구조재	전해도금	자성 재료
고분자재료	구조재	주물성형	전해도금, LIGA로 제작하는 금속구조물의 몰드로 사용
폴리이미드	구조재	회전 도포	후막 제작 가능, 유연함
Photo Resist	희생층	회전 도포	Lift-off 법 사용
AI	구조, 희생	진공 증착	구조재, 희생층으로 사용
Quartz	기능 재료	이방성 식각	압전성, 절연재
ZnO	기능 재료	반도체소자 제조공정	압전성
PZT	기능 재료	후막 공정	압전성
TiNi	기능 재료	반도체소자 제조공정	형상기억합금

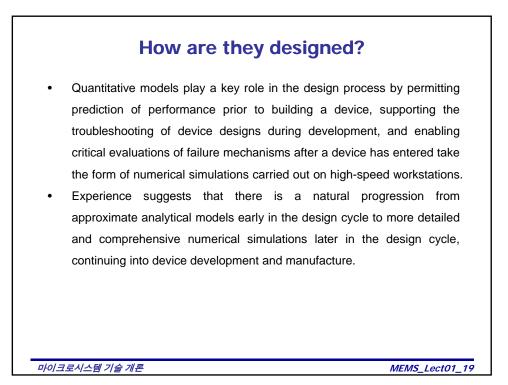
## What are they made of?

- Since the performance of MEMS devices depends on the constitutive properties of the materials from which they are made, the increased diversity of material choices carries with it a requirement for measurement and documentation of their properties.
- Many of these materials are used in thin-film form, and it is well known that thin-film properties can differ from bulk properties.
- The elastic modulus or residual stress of a suspended beam, must be monitored in manufacturing to ensure repeatability from device to device.
- This demands new methods of material property measurement, a subject of increasing importance in the microsystems field.

MEMS\_Lect01\_17

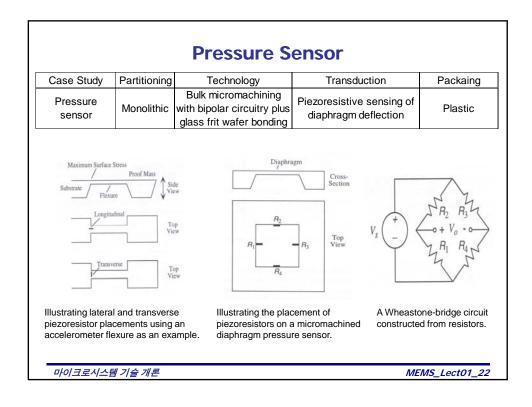
마이크로시스템 기술 개론

How are they designed?
 The design of microsystem requires several different levels of description and detail.
 On one level, the designer must document the need and specifications for a proposed microsystem, evaluate different methods by which it might be fabricated, and , if the device is to become a commercial product, further evaluate the anticipated manufactured cost.
 At another level, for each proposed approach, one must deal with details of partitioning the system into components, materials selection and the corresponding fabrication sequence for each component, methods for packaging and assembly, and means to assure adequate calibration and device uniformity during manufacture.

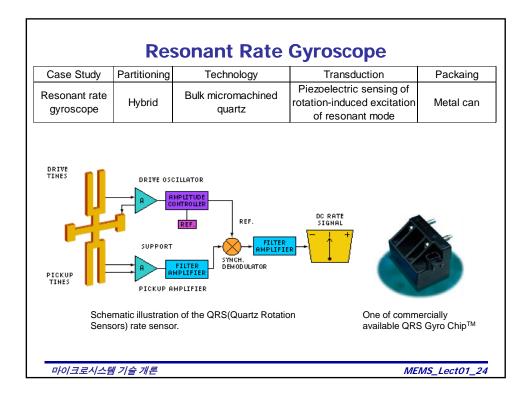


	n Planning Corporation Mai f 1996 product volume and US\$).		
Devices	Applications	1996	2003
Inertial Measurement	Accelerometers and rate gyros	350 - 540	700 - 1,400
Microfluidics	Ink-jet printers, mass-flow sensors, biolab chips	400 - 500	3,000 - 4,450
Optics	Optical switches, displays	25 -40	440 - 950
Pressure Measurement	Automotive, medical, industrial	390 - 760	1,100 - 2,150
RF Devices	Cell phone components, devices for radar	none	40 - 120
Other Devices	Microrelays, sensors, disk heads	510 - 1,050	1,230 - 2,470

Case Study	Partitioning	Technology	Transduction	Packaing
Pressure sensor	Monolithic	Bulk micromachining with bipolar circuitry plus glass frit wafer bonding	Piezoresistive sensing of diaphragm deflection	Plastic
Accelerometer	Monolithic	Surface micromachining with CMOS circuitry	Capacitive detection of proof-mass motion	Metal can
Resonant rate gyroscope	Hybrid	Bulk micromachined quartz	Piezoelectric sensing of rotation-induced excitation of resonant mode	Metal can
Electrostatically driven display	Hybrid	Surface micromachining using XeF <sub>2</sub> release	Electrostatic actuation of suspended tensile ribbons	Bonded glass device cap plus direct wire bond to ASIC
DNA amplification with PCR	Hybrid	Bonded etched	Pressure-driven flow across temperature- controlled zones	Microcapillaries attached with adhesive
Catalytic combustible gas sensor	Hybrid	Surface micromachined with selective deposition of catalyst	Resistance change due to heat of reaction of combustible gas	Custom mounting for research use



Case Study	Partitioning	Technology	Transduction	Packaing
Accelerometer	Monolithic	Surface micromachining with CMOS circuitry	Capacitive detection of proof-mass motion	Metal can
Fixed Electrodes	Anchor	Folded spring Position Sense Region (42 cells) Self-Test Region (12 cells) Shuttle motion (proof mass)		



Case Study	Partitioning	Technology	Transduction	Packaing
Electrostatically driven display	Hybrid	Surface micromachining using XeF <sub>2</sub> release	Electrostatic actuation of suspended tensile ribbons	Bonded glass device cap plus direct wire bond to ASIC
With no beam de light is refie	effection, With alte	Perfected beam	GLV Pixel (ribbon axis into Diffracted light page) Direction of ribbon motion	Screen

